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Nanomechanical probing and strain tuning of the Curie temperature in suspended $\text{Cr}_2\text{Ge}_2\text{Te}_6$ -based heterostructuresMakars Šiškins¹✉, Samer Kurdi¹, Martin Lee¹, Benjamin J. M. Slotboom¹, Wenyu Xing², Samuel Mañas-Valero³, Eugenio Coronado³, Shuang Jia², Wei Han², Toeno van der Sar¹✉, Herre S. J. van der Zant¹✉ and Peter G. Steeneken^{1,4}✉

Two-dimensional magnetic materials with strong magnetostriction are attractive systems for realizing strain-tuning of the magnetization in spintronic and nanomagnetic devices. This requires an understanding of the magneto-mechanical coupling in these materials. In this work, we suspend thin $\text{Cr}_2\text{Ge}_2\text{Te}_6$ layers and their heterostructures, creating ferromagnetic nanomechanical membrane resonators. We probe their mechanical and magnetic properties as a function of temperature and strain by observing magneto-elastic signatures in the temperature-dependent resonance frequency near the Curie temperature, T_C . We compensate for the negative thermal expansion coefficient of $\text{Cr}_2\text{Ge}_2\text{Te}_6$ by fabricating heterostructures with thin layers of WSe_2 and antiferromagnetic FePS_3 , which have positive thermal expansion coefficients. Thus we demonstrate the possibility of probing multiple magnetic phase transitions in a single heterostructure. Finally, we demonstrate a strain-induced enhancement of T_C in a suspended $\text{Cr}_2\text{Ge}_2\text{Te}_6$ -based heterostructure by 2.5 ± 0.6 K by applying a strain of 0.026% via electrostatic force.

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The recent discovery of long range order in two-dimensional (2D) (anti)ferromagnets^{1–3} has triggered extensive studies of 2D materials to experimentally probe magnetism of reduced dimensionality⁴. One material of particular interest is $\text{Cr}_2\text{Ge}_2\text{Te}_6$ (CGT)—a semiconducting ferromagnet with a bulk Curie temperature, $T_C \sim 60\text{--}66$ K^{2,5} with inter- and intra-layer ferromagnetic coupling for any number of layers². Recent progress has been made in manipulating the magnetic order of CGT using electrostatic gating^{6,7}, magnetic field^{2,8}, pressure^{9,10}, ion intercalation¹¹, and via spin-orbit torque^{12,13}. Mechanical strain offers another degree of freedom for such manipulation as bulk CGT was recently shown to exhibit strong spin-lattice coupling^{9,14} and a negative thermal expansion coefficient near T_C ⁵, which is common amongst bulk chromium-based magnetic van der Waals crystals, like CrI_3 , CrCl_3 , CrBr_3 and $\text{Cr}_2\text{Si}_2\text{Te}_6$ ^{15–18}. However, the coupling between magnetic order and strain in thin CGT has not been studied experimentally, as strain is a difficult parameter to control in substrate-supported ultrathin layers^{19,20}.

Emerging nanomechanical methods allow for high-precision strain manipulation and control when 2D materials are suspended forming ultrathin membrane resonators^{21,22}. Due to the combination of low mass, high strength²³ and high frequency tunability^{21,24}, these membranes find potential use in a wide range of sensor applications²⁵ as well as in high-performance nanoelectromechanical systems, where these are used as probes for nonlinear dynamics and condensed matter effects in the materials they are made of²⁶. The resonance frequency of these membranes can be tuned over a large range by strain²¹, which can be controlled both statically²³ and dynamically^{21,22}. Moreover, the difference between the thermal expansion coefficient of suspended 2D material layers and the substrate^{27,28} or other materials in a heterostructure^{29,30} provides additional routes for strain engineering, leading to either stretching or compressing

ultrathin layers. Nanomechanical strain can also be used to probe magnetic states of membrane material²⁷ and switch between these states^{30,31}. The relation between strain, a material's thermal expansion coefficient, and its magnetic properties result in the coupling between mechanical and magnetic degrees of freedom, which allows the investigation of magnetic phase transitions in 2D layered material membranes^{27,30}.

Here, we demonstrate that the magnetic phase transition of suspended thin CGT membranes can be probed mechanically via the temperature-dependent resonance frequency. CGT is known to exhibit high magnetostriction, i.e., a strong magneto-elastic coupling between magnetic order and the lattice^{5,9,14}, that deforms the crystal near T_C ⁵. Thus, to control the strain in thin CGT flakes and deterministically probe the transition temperature, we choose other 2D material layers, WSe_2 and FePS_3 , with positive thermal expansion coefficient and integrate them to form heterostructure membranes with CGT^{29,32–34}, which are important to compensate CGT's negative thermal expansion⁵. We then use these heterostructure membranes to probe and analyze the effect of the mutual interaction between the different 2D materials and CGT, and study the effect of electrostatically induced strain on the ferromagnetic order near T_C .

RESULTS

Mechanical properties of CGT membranes

The force-deflection curve of suspended membranes contains information about mechanical properties of the material. Thus, we first study thin layers of CGT by a static deflection method^{23,35}. We fabricate a freestanding membrane by suspending a mechanically exfoliated thin CGT flake over a circular hole (Fig. 1a). We then apply the atomic force microscopy (AFM) force nanoindentation method^{23,35} to indent the centre of the membrane with the tip of

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an AFM cantilever to cause a deflection of the membrane δ , as shown in Fig. 1b. The force applied to the centre of the membrane, F , is proportional to the stiffness k_c of the cantilever used and its deflection, Δz_c . Using cantilevers with calibrated stiffnesses, we record the force versus membrane deflection curves of this membrane, as depicted in Fig. 1c with filled blue circles. The observed trend can be described by the point-force deflection model for a circular membrane, assuming negligible tip radius compared to the membrane diameter^{23,35}:

$$F = \left(\frac{4\pi E}{3(1-\nu^2)} \frac{h^3}{r^2} \right) \delta + (n_0\pi)\delta + \left(\frac{q^3 E h}{r^2} \right) \delta^3, \quad (1)$$

where E is the Young's modulus of the membrane, r the membrane radius, h the membrane thickness, $\nu = 0.22$ the Poisson ratio of CGT³⁶, n_0 the pre-tension, and $q = 1/(1.05 - 0.15\nu - 0.16\nu^2)$ is a dimensionless geometrical parameter. To our knowledge, the Young's modulus of CGT has not been experimentally studied. We, therefore, extract its Young's modulus E_{CGT} from the experimental data using Eq. (1), as shown in Fig. 1c by the solid magenta line. To obtain a more reliable estimate of E_{CGT} , we measure 18 different

membranes of varying thicknesses ($h = 9.5\text{--}30.1$ nm) and radii ($r = 1\text{--}2.5$ μm). We find a mean value, $E_{\text{CGT}} = 56.2 \pm 8.2$ GPa, as shown in the inset of Fig. 1c. The obtained value of E_{CGT} is consistent with the calculated³⁷ 2D Young's modulus of CGT, $E_{2D} = 41.8$ N m⁻¹, which yields to $E = E_{2D}/h_{2D} = 61.0$ GPa, in which h_{2D} is the single-layer thickness, taken as a third of that of the unit cell of CGT⁵: $h_{2D} = 2.056$ nm/3 $\approx$ 0.685 nm. The standard deviation for our measurements is comparable to that reported in similar experiments on other 2D material membranes^{23,35}. We also found no layer number dependence for the studied range of thicknesses³⁸ (see Supplementary Note 1).

Resonating membranes

In order to study the coupling between the magnetic phase and the mechanical motion, we further investigate the dynamic nanomechanical properties of these membranes as a function of temperature. The temperature dependence of the mechanical resonances of the magnetic membranes is sensitive to changes in the magnetization of the 2D layers³⁰ and the magnetic phase, via a mechanism that couples the specific heat to the membrane tension via the thermal expansion coefficient²⁷. Thus, by observing changes in motion of the membrane at T_c it is possible to probe the ferromagnetic to paramagnetic transition via the mechanical resonance frequency²⁷. To do this, we use a laser interferometry technique^{27,39} (Fig. 2a and "Methods"). A CGT membrane (see the inset of Fig. 2b) is placed in the chamber of an optical cryostat. We use a power-modulated blue laser to opto-thermally excite a fundamental resonance mode of the membrane, and a red laser to measure the change in the reflected signal due to the subsequent displacement of the membrane.

We first measure the resonance peak of the fundamental membrane mode at $T = 4$ K (blue circles in Fig. 2b). We fit the experimental data to a damped harmonic oscillator model (solid magenta line in Fig. 2b) to determine the frequency of the fundamental membrane mode, f_0 . Subsequently, while recording $f_0(T)$ we heat the sample to $T = 78$ K, above the expected T_c of 66 K^{2,5}, and cool it down to $T = 4$ K. We plot the experimental data for the heating (filled blue circles) and the cooling (open blue circles) cycle in Fig. 2c. As the CGT membrane is cooled through the T_c , its resonance frequency f_0 reduces from 19.3 MHz at 78 K to 6.3 MHz at 4 K. To describe the $f_0(T)$ behaviour of CGT, we model the resonance frequency of a circular membrane as:

$$f_0(T) = \sqrt{\left(\frac{2.4048}{2\pi r} \right)^2 \frac{n_{\text{th}}(T)}{\rho h} + f_0^2(T_0)}, \quad (2)$$

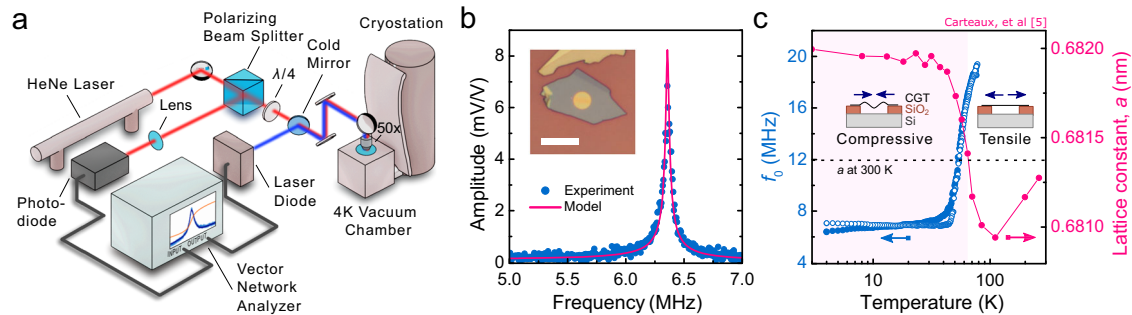


Fig. 2 CGT membrane characterization using laser interferometry. **a** Schematic diagram of the laser interferometry setup. **b** Filled blue circles—measured amplitude of the fundamental resonance peak at $T = 4$ K. Solid magenta line—fit to a damped harmonic oscillator model. The inset shows an optical image of a 17.4 ± 0.3 nm thin CGT membrane of $2 \mu\text{m}$ radius. Scale bar: $8 \mu\text{m}$. **c** The comparison of the measured resonance frequency f_0 of the thin film shown in (b) (see also Supplementary Note 2) and the lattice constant of bulk CGT as a function of temperature. The filled and open blue circles represent the measured data during heating and cooling cycles respectively. The connected magenta circles represent the lattice constant a of bulk CGT as measured by Carteaux et al.⁵. The dashed black horizontal line represents a at $T = 300$ K. The insets show schematics of membrane stretching or buckling at tensile or compressive strain, on the right and left respectively. The pink region indicates the temperature range where compressive strain is dominant and is a guide to an eye.

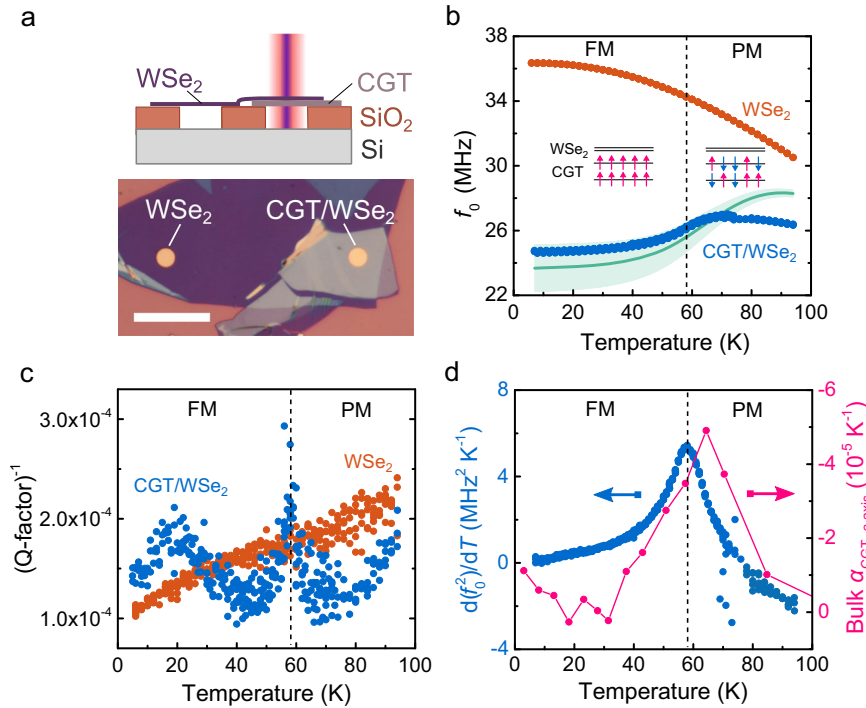


Fig. 3 Mechanical properties of a suspended CGT/WSe₂ (16.7 ± 0.3 nm/6.9 ± 0.1 nm) heterostructure membrane with a radius $r = 2 \mu\text{m}$. **a** Top panel: Schematic cross-section of the sample consisting of the suspended CGT/WSe₂ heterostructure membrane and the reference WSe₂ membrane of the same flake. Bottom panel: Optical image of the sample with specific membranes indicated. Scale bar: 16 μm. **b** Measured resonance frequencies f_0 of the membranes in (a). Solid green line—the fitted model of the resonance frequency of the CGT/WSe₂ heterostructure (Eq. (4)). Light green region—the allowed higher and lower boundary of the model due to the uncertainties in $h_{1,2}$, $E_{1,2}$ and $f_0^2(T_0)$. Insets: Schematic of a CGT/WSe₂ structure with the collinear and random magnetic spin arrangement in a bilayer of CGT in the ferromagnetic (FM) and the paramagnetic (PM) phases respectively. **c** Dissipation factor Q^{-1} as a function temperature. The origin of a broad feature at ~20 K remains unclear and is a subject of future studies. **d** Filled blue circles— $\frac{d(f_0^2)}{dT}$ of the CGT/WSe₂ heterostructure as a function of temperature. Connected magenta circles—the thermal expansion coefficient of bulk CGT⁵. The black vertical dashed lines in (b–d) indicate the measured $T_C^* = 58 \pm 0.5$ K as determined from the peak position of $\frac{d(f_0^2)}{dT}$.

where $f_0(T_0)$ is the resonance frequency at a reference temperature T_0 (e.g., room temperature) due to the contribution of the pre-tension and the bending rigidity, ρ the mass density, $n_{th}(T) = \frac{Eh}{(1-\nu)}\epsilon_{th}$ the thermally accumulated tension, $\epsilon_{th} = -\int_{T_0}^T (a_{CGT}(T) - a_{Si}(T)) dT$ the thermal strain at an arbitrary temperature T ,^{27,28} $a_{Si}(T)$ the literature values for thermal expansion coefficient of Si substrate⁴⁰, and $a_{CGT}(T)$ the temperature-dependent thermal expansion coefficient of CGT. Thus, we attribute the observed $f_0(T)$ trend to a large change in the in-plane lattice constants of the unit cell and the resulting negative $a_{CGT}(T)$ near the phase transition, which was also previously reported for bulk CGT⁵. This anomalous lattice expansion, when cooling down from the paramagnetic to the ferromagnetic state, is related to the strong magnetostriction effect at the ferromagnetic ordering temperature T_C in CGT^{5,14} that causes a substantial drop in strain $\epsilon_{th}(T)$ and a corresponding reduction of the membrane tension near T_C .

In Fig. 2c we also plot the change of the in-plane lattice constant, a , of bulk CGT, experimentally obtained by Carreau et al.⁵, as a function of temperature and compare it with the observed resonance frequency. The lattice constant a is shown to be smaller at room temperature (indicated by the black horizontal dashed line) in comparison to temperatures below the paramagnetic to ferromagnetic phase transition (~66 K). Since the lattice constant increases, the suspended part of the flake effectively has a larger volume at $T < T_C$ than at room temperature, indicating a switch from tensile to compressive strain, as indicated by the pink region in Fig. 2c. In this temperature range, the compressively strained suspended flake is likely to sag, wrinkle, or

buckle, which possibly explains a different warming and cooling trend for the resonance frequency $f_0(T)$. Buckling of thicker magnetic CGT layers itself is interesting for the future development of reprogrammable mechanical memory devices at nano- and micro-scale⁴¹, utilizing the bi-stable states of a buckled thick flake^{42,43}. However, in the case of thin membranes, due to the changing resonance mode shape in the compressive strain regime and the potential wrinkling, a comprehensive analysis of $f_0(T)$ using Eq. (2)²⁷ is not reliable for $T < T_C$ and thus cannot be applied directly to resonators made of bare CGT.

Tensile strain in heterostructure membranes

To prevent the compressive strain that can lead to wrinkling in CGT membranes, and controllably probe $f_0(T)$ near and below its phase transition temperature, we fabricate a suspended membrane heterostructure composed of CGT and WSe₂ flakes, shown in Fig. 3. WSe₂ is a material with well-known mechanical properties^{28,44,45} that does not undergo a phase transition from 4 to 300 K⁴⁵. In the heterostructure, its positive thermal expansion coefficient $\alpha_{WSe_2}(T)$ counteracts the negative $a_{CGT}(T)$ near T_C of CGT, such that the total membrane stress remains tensile and f_0 can be used to probe $a(T)$ even below T_C .

We measure $f_0(T)$ of the suspended CGT/WSe₂ heterostructure together with a reference drum of the same WSe₂ flake (Fig. 3b). The $f_{0,WSe_2}(T)$ follows a monotonous increase trend with decreasing temperature (filled orange circles), as expected from its positive $\alpha_{WSe_2}(T)$ ^{28,45}. In contrast, $f_{0,CGT/WSe_2}(T)$ has a downturn with decreasing temperature near the transition temperature

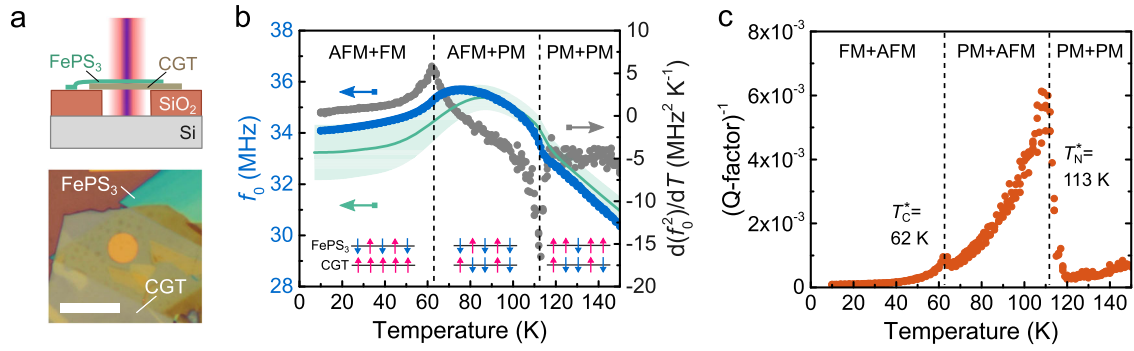


Fig. 4 Mechanical properties of a CGT/FePS₃ (19.8 ± 0.2 nm/ 18.0 ± 0.1 nm) heterostructure membrane with a radius $r = 2.5$ μm. **a Top panel: A schematic cross-section of the suspended heterostructure membrane. Bottom panel: The optical image of the sample with the CGT/FePS₃ heterostructure. Scale bar: 10 μm. **b** Filled blue circles—the measured resonance frequency as a function of temperature. Filled grey circles—the temperature derivative of f_0^2 . Solid green line—the heterostructure resonance frequency model as described by Eq. (4). The light green region indicates the higher and lower boundary of the model allowed due to the uncertainties in $h_{1,2}$, E_{CGT} and $f_0^2(T_0)$. The insets: Schematic pictures of a magnetic spin configuration in FePS₃ and CGT layers in corresponding combinations of antiferromagnetic (AFM), ferromagnetic (FM), and paramagnetic (PM) phases. **c** The dissipation factor Q^{-1} as a function temperature, in which the filled orange circles represent the measured data of the CGT/FePS₃ heterostructure. The black vertical dashed lines in (b) and (c) represent the measured $T_C^* = 62 \pm 1$ K of CGT and $T_N^* = 113 \pm 1$ K of FePS₃ as determined from positions of extrema in $\frac{d(f_0^2)}{dT}$ in (b).**

(filled blue circles). This behaviour is distinct from the bare CGT resonator (Fig. 2c) due to the positive thermal expansion coefficient of the WSe₂ layer, which maintains a tensile total strain of the heterostructure and produces corresponding smaller tuning range of $f_{0,\text{CGT}/\text{WSe}_2}(T)$ near T_C .

We also plot the mechanical dissipation, the inverse of a quality factor $Q^{-1}(T)$, of both the WSe₂ and CGT/WSe₂ resonators in Fig. 3c. A notable peak in $Q_{\text{CGT}/\text{WSe}_2}(T)$ is visible at $T = 58$ K. We attribute this observation to an increase of the thermoelastic damping^{46,47} expected near T_C in magnetic resonators²⁷. This observation is supported by the measured maximum in $\frac{d(f_0^2)}{dT}$ (filled blue circles)²⁷ at 58 ± 0.5 K, the temperature which we define as T_C^* and indicated by the black vertical dashed lines in Fig. 3d. The observed maximum at T_C^* relates to the peak in the thermal expansion coefficient of CGT at T_C (filled magenta circles) that is shifted to lower temperatures in comparison to its bulk values of $60\text{--}66$ K^{2,5}.

We model the resonance frequency of a heterostructure $f_{0,h}(T)$ by modifying Eq. (2) to describe the observations in Fig. 3b. We describe the total thermally accumulated tension of the CGT/WSe₂ heterostructure as a sum of individual tensions in each layer^{29,33}:

$$n_{\text{th}}(T) = n_{\text{th},1}(T) + n_{\text{th},2}(T) = \frac{E_1 h_1}{(1-\nu_1)} \epsilon_{\text{th},1}(T) + \frac{E_2 h_2}{(1-\nu_2)} \epsilon_{\text{th},2}(T). \quad (3)$$

We assume that the slippage between the layers is negligible. Therefore, we obtain the final equation for the resonance frequency of the heterostructure as:

$$f_{0,h}(T) = \sqrt{\left(\frac{2.4048}{2\pi r}\right)^2 \frac{1}{\rho_1 h_1 + \rho_2 h_2} n_{\text{th}}(T) + f_0^2(T_0)}, \quad (4)$$

where n_{th} is given by Eq. (3). We plot the model of Eq. (4) for the CGT/WSe₂ heterostructure in Fig. 3b (solid green line). In doing so, we use the bulk $\alpha_{\text{CGT}}(T)$ values⁵, $\rho_{\text{CGT}} = 6091$ kg m⁻³⁵, $\nu_{\text{CGT}} = 0.22$ ³⁶, and $E_{\text{CGT}} = 56.2 \pm 8.2$ GPa for CGT; $\epsilon_{\text{th},\text{WSe}_2}(T)$ extracted from the measured $f_{0,\text{WSe}_2}(T)$ of the reference drum using equation (2), $\rho_{\text{WSe}_2} = 9320$ kg m⁻³^{44,48}, $\nu_{\text{WSe}_2} = 0.19$ ^{44,49} and $E_{\text{WSe}_2} = 167.1 \pm 0.7$ GPa (measured for this membrane using the nanoindentation method described above, which is consistent with previous studies⁴⁴) for WSe₂; and $f_0(94 \text{ K}) = 27.2 \pm 0.4$ MHz. The resulting model reproduces the experiment qualitatively, yet lacks quantitative agreement above T_C , most likely due to the overestimation of $\alpha_{\text{CGT}}(T)$ for thin layers of CGT in contrast to its bulk value⁵.

Magnetic heterostructures

The presented methodology is not limited exclusively to the use of WSe₂, given that the thermal expansion coefficient of the added material is large and positive. To explore the possibility of detecting two magnetic phase transitions in the same membrane and also the possibility of having emergent properties arising from a coupling between the two flakes, we fabricate a heterostructure membrane made of a ferromagnetic CGT covered by an antiferromagnetic FePS₃ layer, which exhibits positive $\alpha_{\text{FePS}_3}(T)$ ²⁷, as shown in Fig. 4a. Using the methods described above, we measure the resonance frequency of this suspended structure as a function of temperature. In Fig. 4b, we plot experimental $f_0(T)$ (filled blue circles) together with its $\frac{d(f_0^2(T))}{dT}$ (filled grey circles). The temperature derivative of f_0^2 shows two clear extrema, indicated by black vertical dashed lines: the first one at $T_C^* = 62 \pm 1$ K we attribute to the T_C of CGT^{2,5}; the second one at $T_N^* = 113 \pm 1$ K corresponds to the Néel temperature, T_N , of FePS₃^{3,27}. The temperatures at which these peaks appear correspond to the peaks in the specific heat of CGT and FePS₃, as a consequence of its relation to the thermal expansion coefficient $\alpha(T)$ ^{27,50}.

We now analyze the measured $f_0(T)$ curve by plotting the model of Eq. (4) in Fig. 4b (solid green line) for the CGT/FePS₃ heterostructure using material parameters, such as $\alpha(T)$, of CGT and FePS₃ obtained from literature^{5,27,36} and E_{CGT} as determined from Fig. 1. We use $E_{\text{FePS}_3} = 103$ GPa, $\rho_{\text{FePS}_3} = 3375$ kg m⁻³, $\nu_{\text{FePS}_3} = 0.304$ ^{27,51} for FePS₃, and $f_0(150 \text{ K}) = 30.9 \pm 0.7$ MHz. The model describes the experiment well with some deviations at low temperatures similar to the ones described above in Fig. 3c. In addition, we observe two peaks in $Q^{-1}(T)$, displayed in Fig. 4c, that we attribute to an increased thermoelastic damping near the phase transition^{27,46,47}. The temperatures of these peaks coincide with the extrema from Fig. 4b, confirming the phase transitions in CGT and FePS₃.

Electrostatic strain tuning of T_C

Since strong magnetostriction is responsible for the large anomalies in the mechanical response of CGT membranes at T_C ^{5,14} (Fig. 1), we expect that the inverse effect should also be present allowing us to tune the T_C via strain^{27,30}. To study this effect, we fabricate another CGT/WSe₂ heterostructure membrane contacted to Pd electrodes, as shown in Fig. 5a–c. We apply a gate

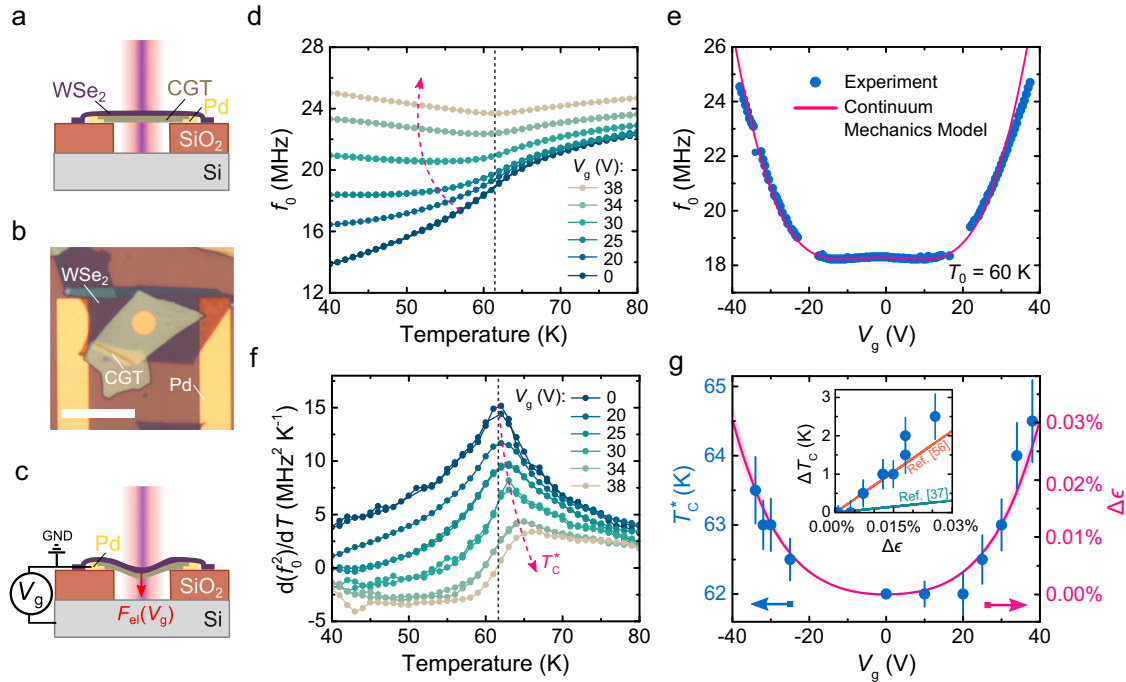


Fig. 5 Curie temperature enhancement as a function of strain in a suspended CGT/WSe₂ heterostructure (19.7 ± 0.1 nm/ 8.5 ± 0.2 nm). **a** The schematic cross-section of the suspended CGT/WSe₂ heterostructure membrane. **b** The optical image of the heterostructure with materials indicated. Membrane radius: $r = 2$ μ m. Scale bar: 12 μ m. **c** The schematics of the electrostatic strain-tuning principle. **d** Measured resonance frequencies f_0 of the heterostructure membrane as a function of temperature for different gate voltages V_g . **e** Filled blue circles—the measured resonance frequency as a function of V_g at 60 K. Solid magenta line—the continuum mechanics model fit^{52,53}. **f** The temperature derivative of f_0^2 as a function of temperature for different V_g . The black vertical dashed lines in **(d)** and **(e)** show the peak position in $\frac{d(f_0^2)}{dT}$ at $V_g = 0$ V. **g** Filled blue circles—the shift in measured T_C^* as a function of V_g extracted from the peak position in **(e)**. Solid magenta line—the estimate of electrostatically induced strain $\Delta\epsilon$ as a function of V_g (see Supplementary Note 3). The shaded magenta region shows the uncertainty in $\Delta\epsilon$. The inset shows $\Delta T_C = T_C^*(V_g) - T_C^*(0\text{ V})$ as a function of added voltage induced strain $\Delta\epsilon$ in addition to calculations from Li and Yang³⁷ (solid green line) and from Dong et al.⁵⁶ (solid orange line). The vertical error bars in T_C^* were estimated from determining the peak position in **(e)** within 2% accuracy in the measured maximum.

voltage V_g between the heterostructure membrane and the bottom Si substrate electrode to induce an electrostatic force, F_{el} , that pulls the membrane down and thus strains the CGT/WSe₂ stack. In Fig. 5d, we show the measured f_0 of the heterostructure membrane as a function of temperature for six different values of V_g . A notable increase of f_0 as a function of V_g is evident which is attributed to the electrostatic strain introduced. To describe the gate dependence of the resonance frequency, we show the $f_0(V_g)$ relationship near the phase transition temperature at $T_0 = 60$ K in Fig. 5e. We fit the measurement data to a continuum mechanics model of a circular membrane resonator^{52,53} (see “Methods”), which describes the experiment well. We thus estimate the electrostatically added strain in CGT layer as:

$$\begin{aligned} \Delta\epsilon &= \epsilon_{el}(V_g) + \epsilon_b(V_g) \\ &\approx \left[\frac{2}{3} \left(\frac{\epsilon_0 r}{8g_0^2 n(T_0)} \right)^2 \right] V_g^4 + \left[\frac{\epsilon_0 \Delta z (1-\nu)}{4g_0^2 n(T_0)} \right] V_g^2, \end{aligned} \quad (5)$$

where ϵ_{el} is the strain due to electrostatic pulling^{30,53}, ϵ_b the strain due to bending^{54,55}, $\Delta z = z_{neut} - z_{CGT}$ the distance from the neutral plane of the heterostructure z_{neut} to the central axis of CGT layer z_{CGT} (see Supplementary Note 3), ϵ_0 the dielectric permittivity of vacuum, and $n(T_0) = 2.538 \pm 0.003$ N m⁻¹ the total tension in the suspended heterostructure at $T_0 = 60$ K (extracted from the fit in Fig. 5e).

Apart from the effect of electrostatically induced strain on $f_0(V_g)$ in Fig. 5d, the characteristic feature in the $f_0(T)$ curve, that we attribute to the Curie temperature of CGT²⁷, shifts to higher temperatures. This trend becomes even more apparent in Fig. 5f, where we plot $\frac{d(f_0^2)}{dT}$ for six different V_g . We extract T_C^* from the peak

positions in $\frac{d(f_0^2)}{dT}$ for multiple V_g and plot it against the gate-induced strain, $\Delta\epsilon$, in Fig. 5g. The observed enhancement in T_C^* qualitatively agrees with the added tensile strain dependence symmetrically both for positive and negative V_g as shown in Fig. 5g. This indicates that the gate-induced strain has a dominant contribution to the change in the $T_C^*(V_g)$ instead of a field effect^{6,7}. In the inset of Fig. 5g, we plot the experimental $\Delta T_C = T_C^*(V_g) - T_C^*(0\text{ V})$ versus the estimated strain $\Delta\epsilon$, together with predictions from density-functional theory calculations for 2D CGT by Li and Yang³⁷, considering the direct exchange interaction (solid green line), and by Dong et al.⁵⁶, attributing the enhancement of T_C to the super-exchange interaction via Cr–Te–Cr bonds (solid orange line). The closer experimental agreement with the results of Dong et al.⁵⁶ suggests that it is the decreasing energy difference between 3d orbitals of Cr and 5p orbitals of Te in nearly $\sim 90^\circ$ Cr–Te–Cr bonds of CGT that is likely to contribute to the enhancement of T_C^* as a function of strain⁵⁶. Interestingly, we observed that the maximal T_C^* increase by mechanical strain was as much as 2.5 ± 0.6 K at $\Delta\epsilon \approx 0.026\%$. This is comparable to what was previously achieved in bulk CGT by applying an out-of-plane magnetic field of 0.7–1 T^{2,8}, proving that strain-based nanomechanical methods provide a compelling route for controlling and probing magneto-elastic coupling in ferromagnetic 2D layers and heterostructures.

DISCUSSION

In conclusion, we have probed the mechanical properties of CGT membranes by both static and dynamic nanomechanical means.

We demonstrated that due to CGT's strong magnetostriction^{5,14} and large negative thermal expansion near T_C , bare CGT membranes experience strong resonance frequency reductions near their ferromagnetic Curie temperature and an accumulation of compressive strain. The compressive strain can produce buckling, wrinkling, or sagging of the CGT layers, which significantly complicates the analysis for nanomechanical measurements of T_C ²⁷. We showed that this challenge can be solved by integrating CGT in heterostructures with other materials with positive thermal expansion coefficients. This methodology can also be applied using materials that have phase transitions themselves, which we demonstrate by probing both T_N of FePS₃ and T_C of CGT within a single measurement of a CGT/FePS₃ heterostructure. The presented measurements and methodologies for nanomechanical characterization of magnetic heterostructures open up possibilities to investigate the magnetic properties that are the result of interfacial interactions in 2D magnetic heterostructures membranes^{57,58}, allowing also for novel magnetic properties to be discovered near the monolayer limit while excluding substrate interactions. In addition, we expect that focused studies of the mechanical dissipation in such heterostructures as a function of temperature and strain could in the future provide more insights to thermodynamics and heat transport in the 2D materials involved^{27,59,60}. Finally, we showed that T_C of CGT can be enhanced by gate-induced electrostatic straining, demonstrating control of magnetic order in these ferromagnetic heterostructures using strain. We anticipate that future studies will lead to the development of membrane devices with gate-controlled magnetic actuation⁶¹ for low-power spintronic applications.

METHODS

Device fabrication and characterization

We first pattern a diced Si/SiO₂ wafer and define circular holes with a radius of $r = 1\text{--}2.5\text{ }\mu\text{m}$ and cavity depth of $g_0 = 285\text{ nm}$ using an e-beam lithography and reactive ion etching. SiO₂ provides an electrical insulation between subsequently transferred 2D material membranes and the bottom Si electrode. To realize electrical contact to some samples for electrostatic experiments, Pd electrodes are pre-patterned on top of Si/SiO₂ chips by a lift-off technique. To create suspended membranes, thin flakes of CGT, FePS₃, and WSe₂ crystals are mechanically exfoliated and transferred on a pre-patterned chip by the all-dry viscoelastic stamping method⁶² directly after exfoliation. Flakes of van der Waals crystals are exfoliated from high quality synthetically grown crystals with known stoichiometry. Using the same method, flakes are deterministically stacked on top of each other forming heterostructures. We stack FePS₃ and WSe₂ flakes on top of CGT to minimize the exposure time of the suspended CGT layers to air. Subsequently, samples are kept in an oxygen-free or vacuum environment to avoid degradation. The total time an average membrane is exposed to air during the fabrication and characterisation is in order of a few tens of minutes. No signs of degradation, such as change in optical contrast of the flakes, its thickness, or apparent disintegration of studied layers, was found during routine characterization of all samples.

Atomic force microscopy characterisation

AFM height profile scans and inspection are performed in tapping mode on a Bruker Dimension FastScan AFM. We use cantilevers with spring constants of $k_c = 30\text{--}40\text{ N m}^{-1}$ for inspection. Error bars on reported thickness values are determined by measuring multiple profile scans of the same flake. For force nanoindentation experiments, we use two different cantilevers with spring constants of $k_c = 8.87 \pm 0.08\text{ N m}^{-1}$ and $k_c = 18.90 \pm 0.11\text{ N m}^{-1}$. k_c for each cantilever was calibrated using thermal and solid surface deflection. We use cantilever tips with a tip radius of $\sim 7\text{--}10\text{ nm}$, as confirmed by scanning electron microscope imaging.

Laser interferometry measurements

The sample is mounted on a xy piezopositioning stage inside a dry optical 4 K cryostat Montana Instruments Cryostation s50. A local sample heater is used to perform temperature sweeps at a rate of $\sim 3\text{ K min}^{-1}$, keeping the

pressure in the chamber below 10^{-6} mbar . A power modulated blue diode laser of $\lambda = 405\text{ nm}$ is used to optothermally excite the motion of the membrane. Membrane displacement is then measured using a laser interferometer with a He-Ne laser beam of $\lambda = 632\text{ nm}$ focused on the suspended membrane. In doing so, the interfering reflections from the membrane and the Si electrode underneath are recorded using a photodiode and processed by a vector network analyzer. All measurements were performed at incident laser powers of $P_{\text{red}} \leq 8\text{ }\mu\text{W}$ and $P_{\text{blue}} \leq 1\text{ }\mu\text{W}$. Laser spot size is on the order of $\sim 1\text{ }\mu\text{m}$. During the data acquisition it is checked for all membranes that resonance frequency changes due to laser heating are insignificant. During data acquisition temperature is kept constant with $\sim 10\text{ mK}$ stability by the local heater and a closed feedback loop controller. The uncertainty in measured transition temperatures is estimated from determining the peak position in $\frac{d(f_g)}{dT}$ within 2% accuracy in the measured maximum.

Continuum mechanics model of electrostatically strained circular membrane

A membrane suspended over a circular cavity forms a capacitor with a bottom gate electrode underneath. The change in gate voltage causes the membrane to deflect, tuning the tension and producing a shift in the resonance frequency. The resonance frequency of the fundamental vibration mode of the drum as a function of gate voltage is described as⁵²:

$$f_0(V_g) = \frac{1}{2\pi} \sqrt{\frac{1}{m_{\text{eff}}} \left[\frac{2\pi E h \epsilon_0}{1 - \nu^2} + \frac{8\pi E h}{(1 - \nu^2)r^2} \delta_g^2 - \frac{1}{2} \frac{\partial^2 C_g}{\partial z^2} V_g^2 \right]}, \quad (6)$$

where $\delta_g \approx \frac{\epsilon_0 r^2}{8g_0^2 n(T_0)} V_g^2$ is the maximal deflection at the membrane centre⁵³, $\frac{\partial^2 C_g}{\partial z^2} \approx \frac{0.542 \epsilon_0 \pi r^2}{g_0^2}$ the second derivative of capacitance^{53,63}, and $m_{\text{eff}} = 0.27 \rho h \pi r^2$ the effective mass. In the case of a heterostructure membrane, material parameters are substituted for the heterostructure analogues²⁹: $E = \frac{E_1 h_1 + E_2 h_2}{h_1 + h_2}$, $\rho = \frac{\rho_1 h_1 + \rho_2 h_2}{h_1 + h_2}$, $\nu = \frac{\nu_1 h_1 + \nu_2 h_2}{h_1 + h_2}$, and $h = h_1 + h_2$. For the CGT/WSe₂ heterostructure ($19.7 \pm 0.1\text{ nm}/8.5 \pm 0.2\text{ nm}$) in Fig. 5 we use the following material parameters: $E = 89.6\text{ GPa}$, $h = 28.2\text{ nm}$, $\nu = 0.21$, $\rho = 7064\text{ kg m}^{-3}$. We extract $\epsilon = 0.079 \pm 0.004\%$, $\frac{\partial^2 C_g}{\partial z^2} = 3.46 \pm 0.11\text{ mFm}^{-2}$ and $m_{\text{eff}} = 996.45\text{ fg}$ from the fit in Fig. 5e, that are close to the expected values^{53,63} of $\frac{\partial^2 C_g}{\partial z^2} = 2.61\text{ mFm}^{-2}$ and $m_{\text{eff}} = 675.9\text{ fg}$.

DATA AVAILABILITY

The numerical data that support the findings of this study are available from the data repository. The experimental data shown in figures of the manuscript can be downloaded from the Zenodo online repository at <https://doi.org/10.5281/zenodo.6501917>

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AUTHOR CONTRIBUTIONS

M.Š., S.K., E.C., H.S.J.v.d.Z., T.v.d.S., and P.G.S. conceived the experiments. M.Š. performed the laser interferometry measurements. M.Š. and M.L. fabricated and inspected the samples. S.M.-V. and E.C. synthesized and characterized the FePS_3 crystals. W.X., S.J., and W.H. synthesized and characterized the $\text{Cr}_2\text{Ge}_2\text{Te}_6$ crystals. M.Š., S.K., and B.J.M.S. analyzed and modelled the experimental data. H.S.J.v.d.Z., T.v.d.S., and P.G.S. supervised the project. The paper was jointly written by all authors with a main contribution from M.Š. All authors discussed the results and commented on the paper.

COMPETING INTERESTS

The authors declare no competing interests.

ADDITIONAL INFORMATION

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